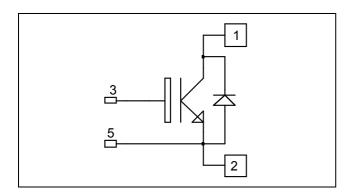


Single switch NPT IGBT Power Module

$$V_{CES} = 600V$$

 $I_{C} = 360A$ @ $T_{C} = 80^{\circ}C$



Application

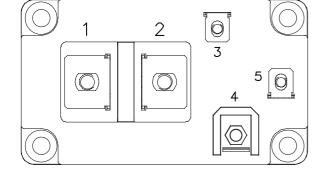
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- M6 connectors for power
- M4 connectors for signal
- High level of integration

Benefits

- Outstanding performance at high frequency
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- **RoHS Compliant**



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	450	
	Continuous Conector Current	$T_C = 80^{\circ}C$	360	Α
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	720	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	1560	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	800A@520V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
1	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25^{\circ}C$			500	μΑ
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 600V$	$T_j = 125$ °C			1	mA
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.95	2.45	V
		$I_C = 400A$ $T_j = 125^{\circ}C$		2.2		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 6mA$		4.5	5.5	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				1200	nA

Dynamic Characteristics

•	Characteristic Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} =$	$V_{GE} = 0V, V_{CE} = 25V$ f = 1MHz		17		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			1.6		111
Q_{G}	Gate charge	V _{GE} =15V, I _C =400A V _{CE} =300V			1		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		150		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$			72		
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm C} = 400 {\rm A}$			530		115
$T_{\mathbf{f}}$	Fall Time	$R_G = 8\Omega$			40		
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_{C} = 400A$ $R_{G} = 8\Omega$		160		ns
T_{r}	Rise Time				75		
$T_{d(off)}$	Turn-off Delay Time				550		
$T_{\rm f}$	Fall Time	-			50		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$	$T_j = 125$ °C		18.6		mJ
E_{off}	Turn off Energy	$I_C = 400A$ $R_G = 8\Omega$	$T_j = 125$ °C		17.3		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 360V$ $t_p \le 10\mu s$; $T_j = 125^{\circ}C$			1800		A

Reverse diode ratings and characteristics

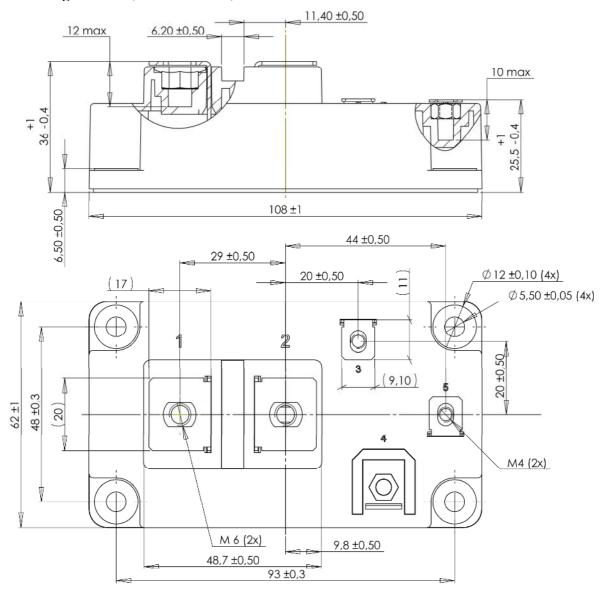
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RRM}	Maximum Reverse Leakage Current	$V_R = 600V$	$T_j = 25$ °C $T_i = 125$ °C			750 1000	μΑ
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		400		A
V_{F}	Diode Forward Voltage	$I_F = 400A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.25	1.6	V
v _F			$T_{i} = 125^{\circ}C$		1.2		·
,	Reverse Recovery Time		$T_i = 25^{\circ}C$		150		
t_{rr}		$T_{\rm j} = 125^{\circ}{\rm C}$		250		ns	
Q _{rr}	Reverse Recovery Charge	$I_F = 400A$ $V_R = 300V$	$T_j = 25^{\circ}C$		27		μС
	Reverse Recovery Charge	$di/dt = 4400A/\mu s$	$T_j = 125$ °C		44		μΟ
Е	В		$T_j = 25^{\circ}C$		5.6		mJ
E_{rr}	Reverse Recovery Energy		$T_{j} = 125^{\circ}C$		9.2		1113



Thermal and package characteristics

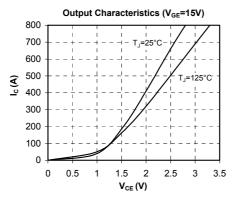
Symbol	Characteristic		Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance	IGBT			0.08	°C/W
KthJC		Diode			0.15	C/ VV
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V
T_{J}	Operating junction temperature range		-40		150	
T_{STG}	Storage Temperature Range		-40		125	°C
$T_{\rm C}$	Operating Case Temperature		-40		125	
Torque	Mounting torque	M6	3		5	N.m
		M4	1		2	11.111
Wt	Package Weight				350	g

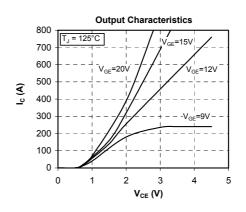
D4 Package outline (dimensions in mm)

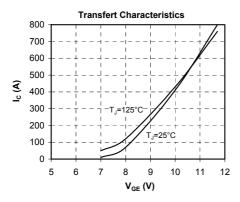


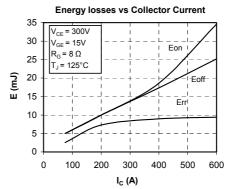


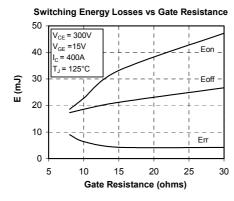
Typical Performance Curve

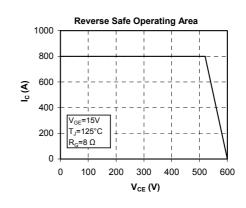


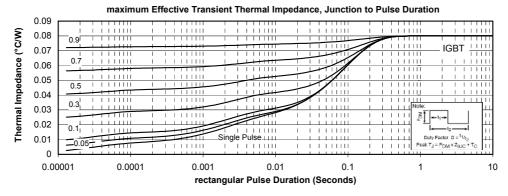




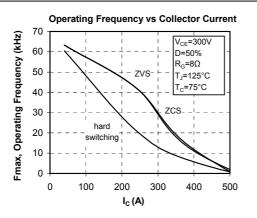


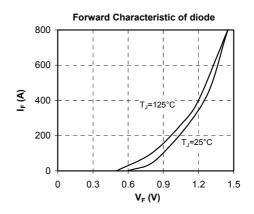


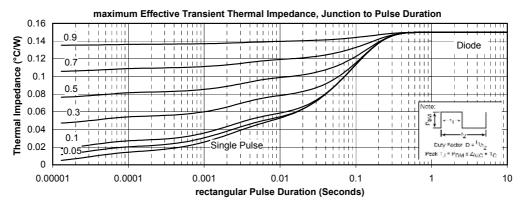














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